

PROCEEDINGS OF SPIE

***Quantum Dots and Nanostructures:
Synthesis, Characterization, and
Modeling IX***

**Kurt G. Eyink
Frank Szmulowicz
Diana L. Huffaker**
Editors

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Contents

- v *Conference Committee*
- vii *Spinoptics: Spin degeneracy removal in nanostructures (Plenary Paper) [8269-100]*
V. Kleiner, N. Shitrit, E. Hasman, Technion-Israel Institute of Technology (Israel)

SESSION 1 HYBRID STRUCTURES

- 8271 04 **Effect of silver nanoparticles on the spectral properties of rare-earth ions in a sodium borate glass** [8271-03]
V. O. Obadina, B. Rami Reddy, Alabama A&M Univ. (United States)
- 8271 06 **Optical properties of mesogen-coated gold nanoparticles** [8271-05]
J. Dintinger, Ecole Polytechnique Fédérale de Lausanne (Switzerland); B.-J. Tang, The Univ. of Hull (United Kingdom); X. Zeng, The Univ. of Sheffield (United Kingdom); T. Kienzler, Friedrich-Schiller-Univ. Jena (Germany); G. H. Mehl, The Univ. of Hull (United Kingdom); G. Ungar, C. Rockstuhl, The Univ. of Sheffield (United Kingdom); T. Scharf, Friedrich-Schiller-Univ. Jena (Germany)

SESSION 2 COLLOIDAL QUANTUM DOTS

- 8271 08 **Morphology, optical properties, charge transfer, and charge transport in nanocrystalline quantum dots (Invited Paper)** [8271-08]
S. Biswas, H. Jung, M. Stroschio, M. Dutta, Univ. of Illinois at Chicago (United States)
- 8271 09 **Transport properties of mid-infrared colloidal quantum dot films** [8271-09]
E. Lhuillier, S. Keuleyan, P. Guyot-Sionnest, The Univ. of Chicago (United States)
- 8271 0A **Fourier spectroscopy on PbS quantum dots** [8271-10]
B. Ullrich, J. S. Wang, X. Y. Xiao, G. J. Brown, Air Force Research Lab. (United States)

SESSION 3 OPTICAL DEVICES I

- 8271 0D **Single photon sources for quantum information applications (Invited Paper)** [8271-13]
S. Höfling, C. Schneider, T. Heindel, M. Lermer, Julius-Maximilians-Univ. Würzburg (Germany); T. B. Hoang, Technische Univ. Eindhoven (Netherlands); J. Beetz, T. Braun, Julius-Maximilians-Univ. Würzburg (Germany); L. Balet, Technische Univ. Eindhoven (Netherlands) and Ecole Polytechnique Fédérale de Lausanne (Switzerland); N. Chauvin, Technische Univ. Eindhoven (Netherlands); L. Li, Ecole Polytechnique Fédérale de Lausanne (Switzerland); S. Reitzenstein, Julius-Maximilians-Univ. Würzburg (Germany); A. Fiore, Technische Univ. Eindhoven (Netherlands); M. Kamp, A. Forchel, Julius-Maximilians-Univ. Würzburg (Germany)
- 8271 0E **Reducing dephasing in coupled quantum dot-cavity systems by engineering the carrier wavefunctions** [8271-14]
A. Nysteen, P. Kaer, J. Mørk, Technical Univ. of Denmark (Denmark)

SESSION 4 NOVEL MATERIALS

- 8271 0I **Evolution of micro-spikes on silicon surface etched by femtosecond laser with different fabrication conditions (Invited Paper)** [8271-18]
Y. Peng, Y. M. Zhu, Univ. of Shanghai for Science and Technology (China)
- 8271 0J **Hyperspectral polarized light scattering for dense nanomaterials characterization** [8271-19]
R. Ceolato, N. Riviere, L. Hespel, ONERA (France); B. Biscans, CNRS-LGC (France)

SESSION 5 GROWTH AND CHARACTERIZATION

- 8271 0L **Semiconductor quantum nanostructures by droplet epitaxy (Invited Paper)** [8271-21]
S. Sanguinetti, S. Bietti, C. Somaschini, Univ. degli Studi di Milano-Bicocca (Italy)
- 8271 0N **The impact of growth rate and barrier thickness on the thermal stability of photoluminescence for coupled InAs/GaAs quantum dot heterostructures with quaternary(InAlGaAs) capping** [8271-23]
A. Mandal, Indian Institute of Technology Bombay (India); U. Verma, Indian Institute of Technology Rajasthan (India); S. Chakrabarti, Indian Institute of Technology Bombay (India)
- 8271 0O **Ground state energy trend in single and multilayered coupled InAs/GaAs QDs capped with InGaAs layers: effect of thickness of InGaAs layer and the RTA treatment** [8271-24]
S. Jejurikar, A. Mishra, P. Bhat, S. Chakrabarti, Indian Institute of Technology Bombay (India)
- 8271 0R **Increase in photoluminescence intensity of InAs columnar quantum dots on InP(001) substrate by increasing indium and phosphorous composition in InGaAsP barrier layers** [8271-27]
S. Okumura, N. Yasuoka, Photonics Electronics Technology Research Association (Japan) and Fujitsu Ltd. (Japan); K. Kawaguchi, Fujitsu Labs., Ltd. (Japan); Y. Tanaka, Photonics Electronics Technology Research Association (Japan) and Fujitsu Ltd. (Japan); M. Ekawa, Fujitsu Labs., Ltd. (Japan)

SESSION 6 OPTICAL DEVICES II

- 8271 0S **Improvement of temperature stability in columnar quantum dots by introducing side barriers with larger bandgap energy for semiconductor optical amplifiers** [8271-29]
N. Yasuoka, S. Okumura, Fujitsu Labs., Ltd. (Japan) and Photonics Electronics Technology Research Association (Japan); H. Ebe, Fujitsu Labs., Ltd. (Japan); Y. Tanaka, Fujitsu Labs., Ltd. (Japan) and Photonics Electronics Technology Research Association (Japan); M. Ekawa, Y. Nakata, Fujitsu Labs., Ltd. (Japan); M. Sugawara, QD Laser Inc. (Japan); Y. Arakawa, Institute for Nano Quantum Information Electronics (Japan) and The Univ. of Tokyo (Japan)

POSTER SESSION

- 8271 0V **Computational analysis of the effects of gain material inclusion in engineered metal nanostructures** [8271-06]
J. Duan, Air Force Research Lab. (United States) and General Dynamics Information Technology (United States); R. Pachter, Air Force Research Lab. (United States)

Author Index

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Holger Eisele, Technische Universität Berlin (Germany)
Sven Hoefling, Julius-Maximilians-Universität Würzburg (Germany)
- 4 Novel Materials
Jian Xu, The Pennsylvania State University (United States)

- 5 Growth and Characterization
Gregory J. Salamo, University of Arkansas (United States)
- 6 Optical Devices II
Baolai Liang, University of California, Los Angeles (United States)